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PII: S0254-0584(17)30550-3

DOI: 10.1016/j.matchemphys.2017.07.041

Reference: MAC 19848

To appear in: Materials Chemistry and Physics

Received Date: 27 November 2016

Revised Date: 18 June 2017
Accepted Date: 11 July 2017

Please cite this article as: M.F. Mostafa, S.S. Elkhiyami, S.A. Alal, Discontinuous transition from insulator to semiconductor induced by phase change of the new organic-inorganic hybrid [(CH₂)₇(NH₃)₂]CoBr₄, *Materials Chemistry and Physics* (2017), doi: 10.1016/j.matchemphys.2017.07.041.

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Discontinuous transition from insulator to semiconductor induced by phase change of the new organic- inorganic hybrid $[(CH_2)_7(NH_3)_7]CoBr_4$

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Abstract

[(CH₂)₇(NH₃)₂]CoBr₄, triclinic crystal has a space group P1 with two molecules per asymmetric unit cell (Z = 2). Unit cell dimensions are: a = 7.6588 (3) Å, b = 10.5160 (3) Å, c = 11.3319 (5) Å, $\alpha = 66.745$ (2) °, $\beta = 77.2258$ (13) °, $\gamma = 88.001$ (2) °, volume = 816.37(5) Å³ and calculated density = 2.078 Mgm⁻³. The structure consists of $[CoBr_4]^{2-}$ tetrahdera separated by heptane diammonium layers. The organic hydrocarbon layers' pack in a stacked herring-bone manner hydrogen bonded to the halide ions. Lattice potential energy is $U_{pot} = 1827.7$ kJ/mol, and molecular volume $V_m = 0.408$ nm³. Calorimetric (DSC) measurements indicate phase transitions at T_1 =350±1 K (ΔS = 22.7 J/K-mol) and 335 K ($\Delta S = 10.5$ J/K-mol). Dielectric and conductivity as a function of temperature (300<T K< 420) and frequency (0.21 < f (kHz) < 60) were investigated. Abrupt change from an insulator to semiconductor behavior takes place around T₁. At low temperatures, thermally activated Arrhenius behavior is observed with frequency dependent, temperature independent activation energy. At high temperatures conductivity and activation energy are frequency and temperature dependent implying non-Arrhenius type behavior where the charged particles experience different potentials for local and long distance movements. Conduction takes place via correlated barrier hopping with maximum barrier height $W_M = 0.015 \text{ eV}$.

Key words: X-ray crystal structure, Phase transition, Dielectric constant, conductivity.

PACS No: 61.66, 67, 77.22

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[†]In partial fulfillment of Ph.D.

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